

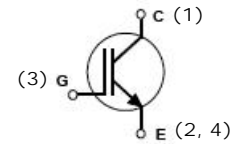
**PRELIMINARY DATASHEET**  
**1200V, 100A IGBT in SPT+ Technology**  
**In SOT227 Package**

**APPLICATIONS**

- General inverters
- Uninterruptible power supplies (UPS)
- Welders

**FEATURES**

- Ultra low loss IGBT
- Highly rugged SPT design
- Pb-free finished; **RoHS Compliant**



**MAXIMUM RATINGS<sup>1</sup>**

Parameter	Symbol	Value	Units
Collector-emitter voltage	$V_{CE}$	1200	V
DC collector current $T_c = 80\text{ }^\circ\text{C}$	$I_c$	100	A
Peak collector current, limited by $T_{jmax}$	$I_{CM}$	200	
Gate-emitter voltage	$V_{GES}$	$\pm 20$	V
IGBT short circuit SOA $V_{CC} = 900\text{V}, V_{CEM} \leq 1200\text{V}, V_{GE} \leq 15\text{V}, T_{vj} = 125^\circ\text{C}$	$t_{PSC}$	10	$\mu\text{s}$
Operating junction and storage temperature	$T_j, T_{stg}$	-40... +150	$^\circ\text{C}$

**Thermal and Isolation Characteristics**

Parameter	Symbol	Max. Value	Units
<b>Characteristics</b>			
IGBT thermal resistance, junction to case	$R_{thJC}$	0.2	K/W
Isolation voltage, RMS (measured between terminals and mounting base, 50-60 Hz, for 1-2 seconds)	$V_{ISO}$	3000	V

**ELECTRICAL CHARACTERISTICS<sup>2</sup>**, at  $T_j = 25^\circ\text{C}$ , unless otherwise specified

Parameter	Symbol	Conditions	Value			Unit
			Min.	Typ.	Max.	
<b>Static Characteristics</b>						
Collector-emitter breakdown voltage	$V_{(BR)CES}$	$V_{GE} = 0\text{V}, I_C = 1\text{mA}$	1200	-	-	V
Collector-emitter saturation voltage at $T = 25^\circ\text{C}$ at $T = 125^\circ\text{C}$	$V_{CE(sat)}$	$V_{GE} = 15\text{V},$ $I_C = 100\text{A}$	-	1.8 2.0	-	
Gate-emitter threshold voltage	$V_{GE(th)}$	$I_C = 4\text{mA}, V_{CE} = V_{GE}$	5	6.2	7	
Zero gate voltage collector current at $T = 25^\circ\text{C}$ at $T_j = 125^\circ\text{C}$	$I_{CES}$	$V_{CE} = 1200\text{V}, V_{GE} = 0$	-	-	100	$\mu\text{A}$
Gate-emitter leakage current	$I_{GES}$	$V_{CE} = 0\text{V}, V_{GE} = 20\text{V}$ at $T = 125^\circ\text{C}$	-200	-	200	nA
Short Circuit Current	$I_{SC}$	$V_{CC} = 900\text{V}, V_{GE} = 15\text{V}$ $t_{psc} \leq 10\mu\text{s}$ $V_{CEM} = 1200\text{V}$ at $T_C = 125^\circ\text{C}$	-	470	-	A

**ELECTRICAL CHARACTERISTICS<sup>2</sup>**, at  $T_j = 25^\circ\text{C}$ , unless otherwise specified

<b>Dynamic Characteristics</b>						
Input capacitance	$C_{iss}$	$V_{CE} = 25\text{V},$ $V_{GE} = 0\text{V},$ $f = 1\text{MHz}$	-	7.43	-	nF
Output capacitance	$C_{oss}$		-	0.52	-	
Reverse transfer capacitance	$C_{rss}$		-	0.34	-	
Gate Charge	$Q_g$	$V_{CE} = 600\text{V}, I_C = 100\text{A}$ $V_{GE} = -15\text{V}, 15\text{V}$	-	1050	-	nC

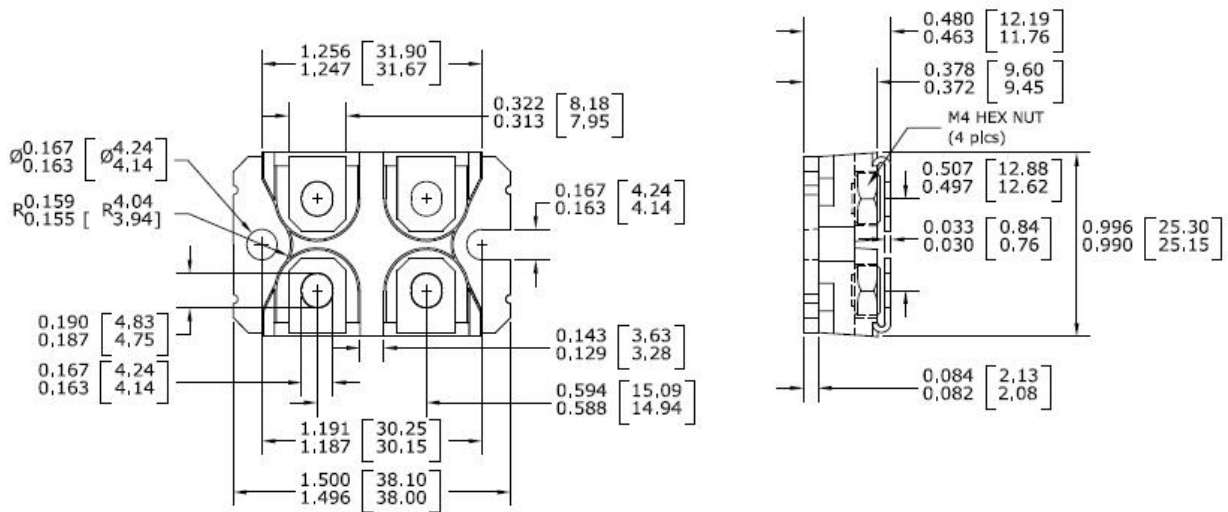
**SWITCHING CHARACTERISTICS<sup>2</sup>**, at  $T_j = 25^\circ\text{C}$ , unless otherwise specified

Parameter	Symbol	Conditions	Value			Unit
			Min.	Typ.	Max.	
<b>IGBT Characteristics</b>						
Turn-on delay time	$t_{d(on)}$	$V_{CC} = 600\text{V}, I_C = 100\text{A},$ $V_{GE} = \pm 15\text{V},$ $R_G = 10\Omega, L_\sigma = 60\text{nH}$ Inductive Load	-	125	-	ns
Rise time	$t_r$		-	60	-	
Turn-off delay time	$t_{d(off)}$		-	420	-	
Fall time	$t_f$		-	60	-	
Turn-on energy	$E_{on}$		-	8.6	-	mJ
Turn-off energy	$E_{off}$		-	6.8	-	

**SWITCHING CHARACTERISTICS<sup>2</sup>**, at  $T_j = 125^\circ\text{C}$ , unless otherwise specified

Parameter	Symbol	Conditions	Value			Unit
			Min.	Typ.	Max.	
<b>IGBT Characteristics</b>						
Turn-on delay time	$t_{d(on)}$	$V_{CC} = 600\text{V}$ , $I_c = 100\text{A}$ , $V_{GE} = \pm 15\text{V}$ , $R_G = 10\Omega$ , $L_\sigma = 60\text{nH}$ Inductive Load	-	135	-	ns
Rise time	$t_r$		-	60	-	
Turn-off delay time	$t_{d(off)}$		-	490	-	
Fall time	$t_f$		-	75	-	
Turn-on energy	$E_{on}$		-	12.4	-	mJ
Turn-off energy	$E_{off}$	-	10.8	-		

- 1) Maximum rated values indicate limits beyond which damage to the device may occur per IEC 60747-9  
 2) Characteristic values according to IEC 60747-9

**Package Outline Drawing**


CAUTION: These devices are ESD sensitive. Use proper handling procedure.

**Disclaimer**

These specifications may not be considered as a guarantee of components characteristics. Components have to be tested depending on intended application as adjustments may be necessary. The use of **iQXPRZ Power Inc.** components in life support appliances and systems are subject to written approval of **iQXPRZ Power Inc.**